



30V N-Channel Enhancement Mode MOSFET

Voltage 30 V Current 4.9A

Features

- RDS(ON), VGS@10V, ID@4.9A<38m Ω
- RDS(ON) , VGS@4.5V, ID@3.5A<44mΩA
- RDS(ON) , VGS@2.5V, ID@2.7A<60mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

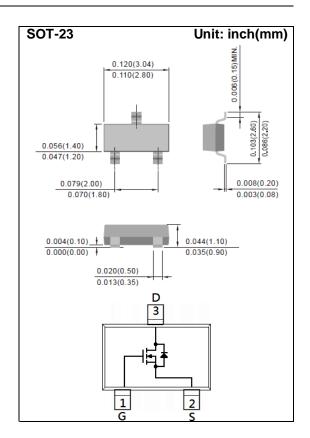
Mechanical Data

• Case: SOT-23 Package

Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: A00



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	30	V
Gate-Source Voltage		V_{GS}	<u>+</u> 12	V
Continuous Drain Current		I _D	4.9	Α
Pulsed Drain Current		I _{DM}	19.6	Α
Power Dissipation	T _a =25°C	P _D	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{ heta JA}$	100	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS} =0V, I_D =250uA	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.5	0.84	1.3	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =4.9A	-	28	38	mΩ
		V _{GS} =4.5V, I _D =3.5A	-	32	44	
		V _{GS} =2.5V, I _D =2.7A	-	45	60	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =30V, V_{GS} =0V	-	0.01	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 12V, V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	Q_g	V _{DS} =15V, I _D =4.9A, V _{GS} =10V (Note 1,2)	-	5.7	-	nC
Gate-Source Charge	Q_gs		-	1.1	-	
Gate-Drain Charge	Q_{gd}		-	1.5	-	
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V,	-	490	-	pF
Output Capacitance	Coss		-	44	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	32	-	
Switching						
Turn-On Delay Time	td _(on)	\/ 45\/ L 40A	-	2	-	ns
Turn-On Rise Time	tr	V_{DD} =15V, I_{D} =4.9A, V_{GS} =10V, R_{G} =3 Ω (Note 1,2)	-	57	-	
Turn-Off Delay Time	td _(off)		-	78	-	
Turn-Off Fall Time	tf		-	79	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	1.5	А
Diode Forward Voltage	V _{SD}	I _S =1.0A, V _{GS} =0V	-	0.77	1.2	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





TYPICAL CHARACTERISTIC CURVES

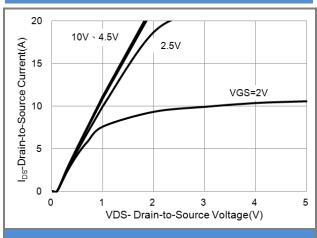


Fig.1 On-Region Characteristics

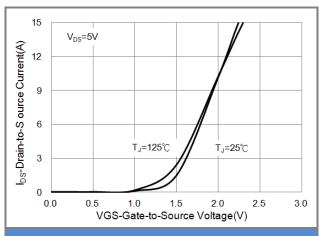


Fig.2 Transfer Characteristics

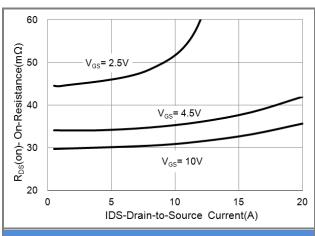


Fig.3 On-Resistance vs. Drain Current

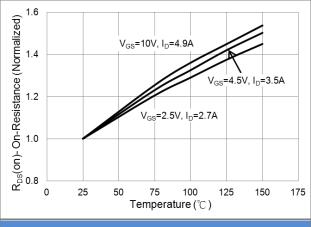
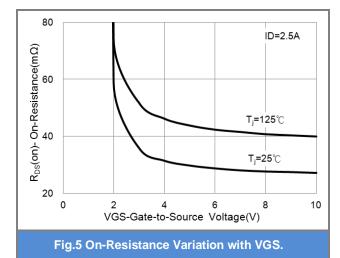
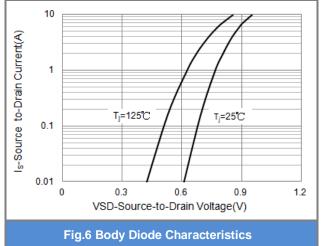


Fig.4 On-Resistance vs. Junction temperature









TYPICAL CHARACTERISTIC CURVES

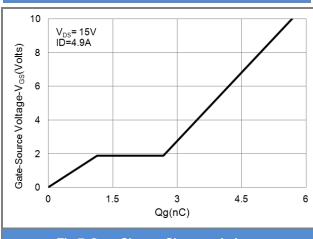


Fig.7 Gate-Charge Characteristics

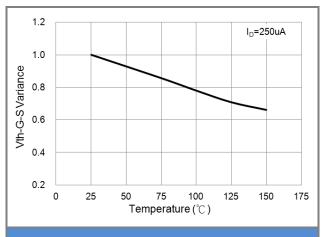


Fig.8 Threshold Voltage Variation with Temperature

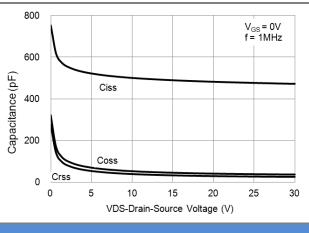


Fig.9 Capacitance vs. Drain-Source Voltage.

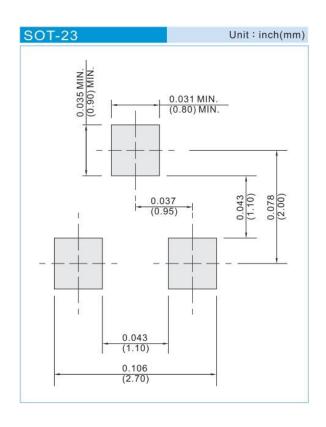




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJA3400_R1_00001	SOT-23	3K pcs / 7" reel	A00	Halogen free
PJA3400 _R2_00001	SOT-23	12K pcs / 13" reel	A00	Halogen free

MOUNTING PAD LAYOUT







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